Intel - EPF6024ATC144-3 Datasheet

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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	196
Number of Logic Elements/Cells	1960
Total RAM Bits	-
Number of I/O	117
Number of Gates	24000
Voltage - Supply	3V ~ 3.6V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	144-LQFP
Supplier Device Package	144-TQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epf6024atc144-3

Table 4 shows FLEX 6000 performance for more complex designs.

Table 4. FLEX 6000 Device Performance for Complex Designs *Note (1)*

Application	LEs Used	Performance			Units
		-1 Speed Grade	-2 Speed Grade	-3 Speed Grade	
8-bit, 16-tap parallel finite impulse response (FIR) filter	599	94	80	72	MSPS
8-bit, 512-point fast Fourier transform (FFT) function	1,182	75 63	89 53	109 43	µS MHz
`a16450` universal asynchronous receiver/transmitter (UART)	487	36	30	25	MHz
PCI bus target with zero wait states	609	56	49	42	MHz

Note:

(1) The applications in this table were created using Altera MegaCore™ functions.

FLEX 6000 devices are supported by Altera development systems; a single, integrated package that offers schematic, text (including AHDL), and waveform design entry, compilation and logic synthesis, full simulation and worst-case timing analysis, and device configuration. The Altera software provides EDIF 2 0 0 and 3 0 0, LPM, VHDL, Verilog HDL, and other interfaces for additional design entry and simulation support from other industry-standard PC- and UNIX workstation-based EDA tools.

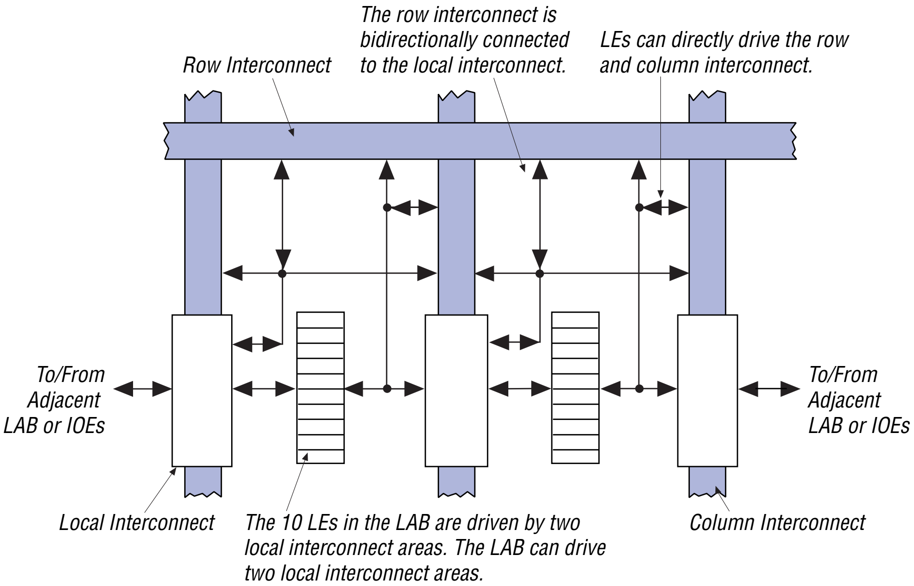
The Altera software works easily with common gate array EDA tools for synthesis and simulation. For example, the Altera software can generate Verilog HDL files for simulation with tools such as Cadence Verilog-XL. Additionally, the Altera software contains EDA libraries that use device-specific features such as carry chains which are used for fast counter and arithmetic functions. For instance, the Synopsys Design Compiler library supplied with the Altera development systems include DesignWare functions that are optimized for the FLEX 6000 architecture.

The Altera development system runs on Windows-based PCs, Sun SPARCstations, and HP 9000 Series 700/800.

See the *MAX+PLUS II Programmable Logic Development System & Software Data Sheet* and the *Quartus Programmable Logic Development System & Software Data Sheet* for more information.

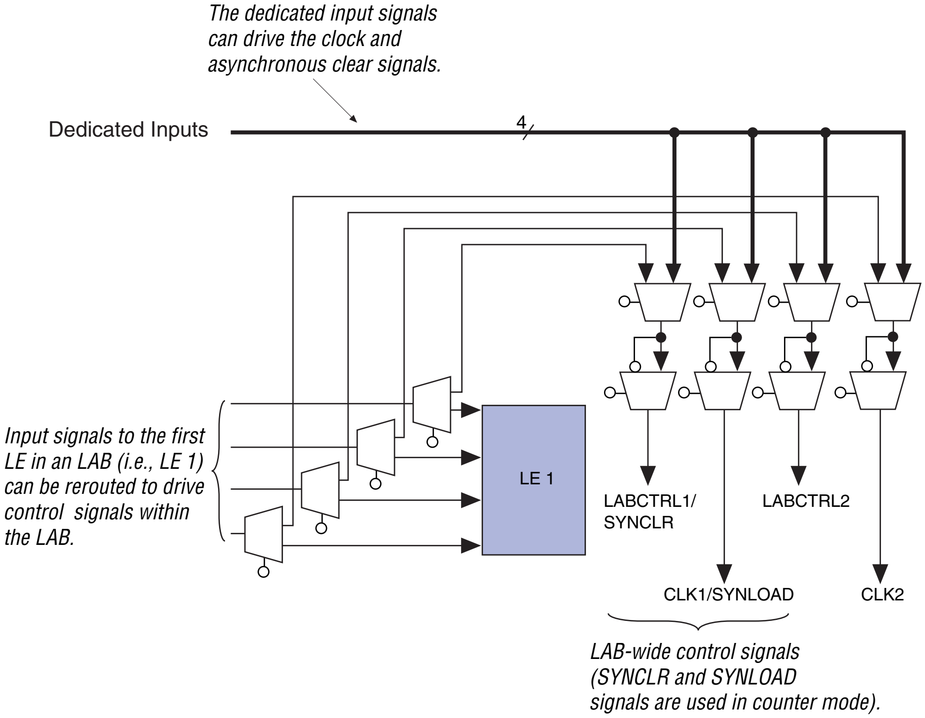
The interleaved LAB structure—an innovative feature of the FLEX 6000 architecture—allows each LAB to drive two local interconnects. This feature minimizes the use of the FastTrack Interconnect, providing higher performance. An LAB can drive 20 LEs in adjacent LABs via the local interconnect, which maximizes fitting flexibility while minimizing die size. See Figure 2.

Figure 2. Logic Array Block



In most designs, the registers only use global clock and clear signals. However, in some cases, other clock or asynchronous clear signals are needed. In addition, counters may also have synchronous clear or load signals. In a design that uses non-global clock and clear signals, inputs from the first LE in an LAB are re-routed to drive the control signals for that LAB. See Figure 3.

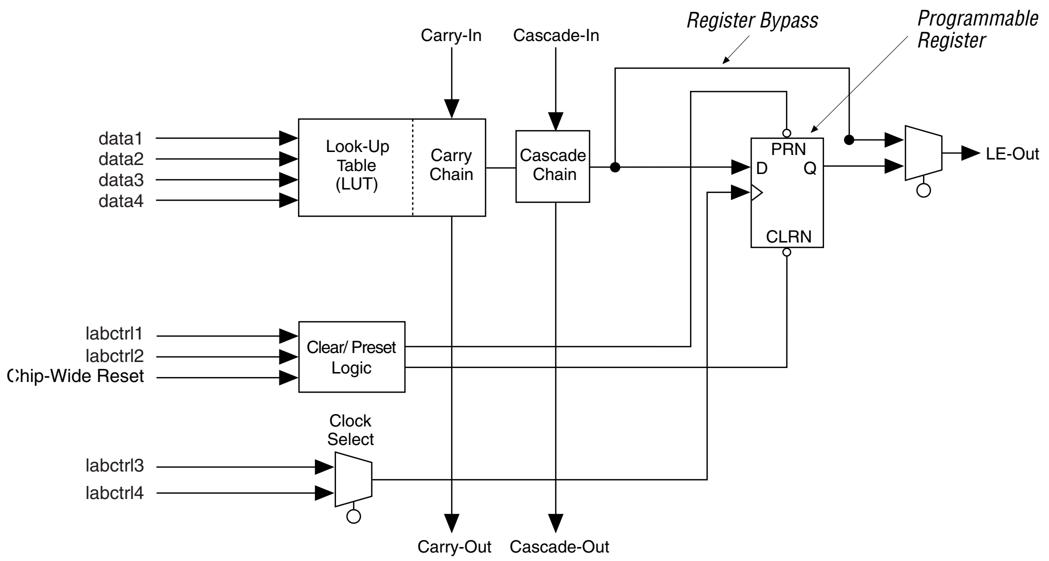
Figure 3. LAB Control Signals



Logic Element

An LE, the smallest unit of logic in the FLEX 6000 architecture, has a compact size that provides efficient logic usage. Each LE contains a four-input LUT, which is a function generator that can quickly implement any function of four variables. An LE contains a programmable flipflop, carry and cascade chains. Additionally, each LE drives both the local and the FastTrack Interconnect. See Figure 4.

Figure 4. Logic Element



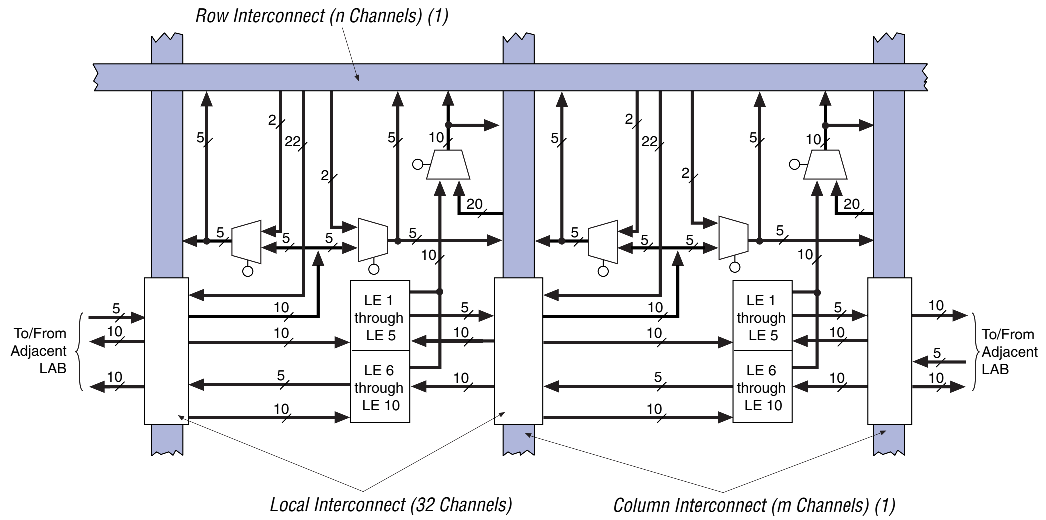
The programmable flipflop in the LE can be configured for D, T, JK, or SR operation. The clock and clear control signals on the flipflop can be driven by global signals, general-purpose I/O pins, or any internal logic. For combinatorial functions, the flipflop is bypassed and the output of the LUT drives the outputs of the LE. The LE output can drive both the local interconnect and the FastTrack Interconnect.

The FLEX 6000 architecture provides two types of dedicated high-speed data paths that connect adjacent LEs without using local interconnect paths: carry chains and cascade chains. A carry chain supports high-speed arithmetic functions such as counters and adders, while a cascade chain implements wide-input functions such as equivalent comparators with minimum delay. Carry and cascade chains connect LEs 2 through 10 in an LAB and all LABs in the same half of the row. Because extensive use of carry and cascade chains can reduce routing flexibility, these chains should be limited to speed-critical portions of a design.

The FastTrack Interconnect consists of column and row interconnect channels that span the entire device. Each row of LABs is served by a dedicated row interconnect, which routes signals between LABs in the same row, and also routes signals from I/O pins to LABs. Additionally, the local interconnect routes signals between LEs in the same LAB and in adjacent LABs. The column interconnect routes signals between rows and routes signals from I/O pins to rows.

LEs 1 through 5 of an LAB drive the local interconnect to the right, while LEs 6 through 10 drive the local interconnect to the left. The `DATA1` and `DATA3` inputs of each LE are driven by the local interconnect to the left; `DATA2` and `DATA4` are driven by the local interconnect to the right. The local interconnect also routes signals from LEs to I/O pins. Figure 9 shows an overview of the FLEX 6000 interconnect architecture. LEs in the first and last columns have drivers on both sides so that all LEs in the LAB can drive I/O pins via the local interconnect.

Figure 9. FastTrack Interconnect Architecture



Row Interconnect (n Channels) (1)

Local Interconnect (32 Channels)

Column Interconnect (m Channels) (1)

Note:

(1) For EPF6010A, EPF6016, and EPF6016A devices, *n* = 144 channels and *m* = 20 channels; for EPF6024A devices, *n* = 186 channels and *m* = 30 channels.

A row channel can be driven by an LE or by one of two column channels. These three signals feed a 3-to-1 multiplexer that connects to six specific row channels. Row channels drive into the local interconnect via multiplexers.

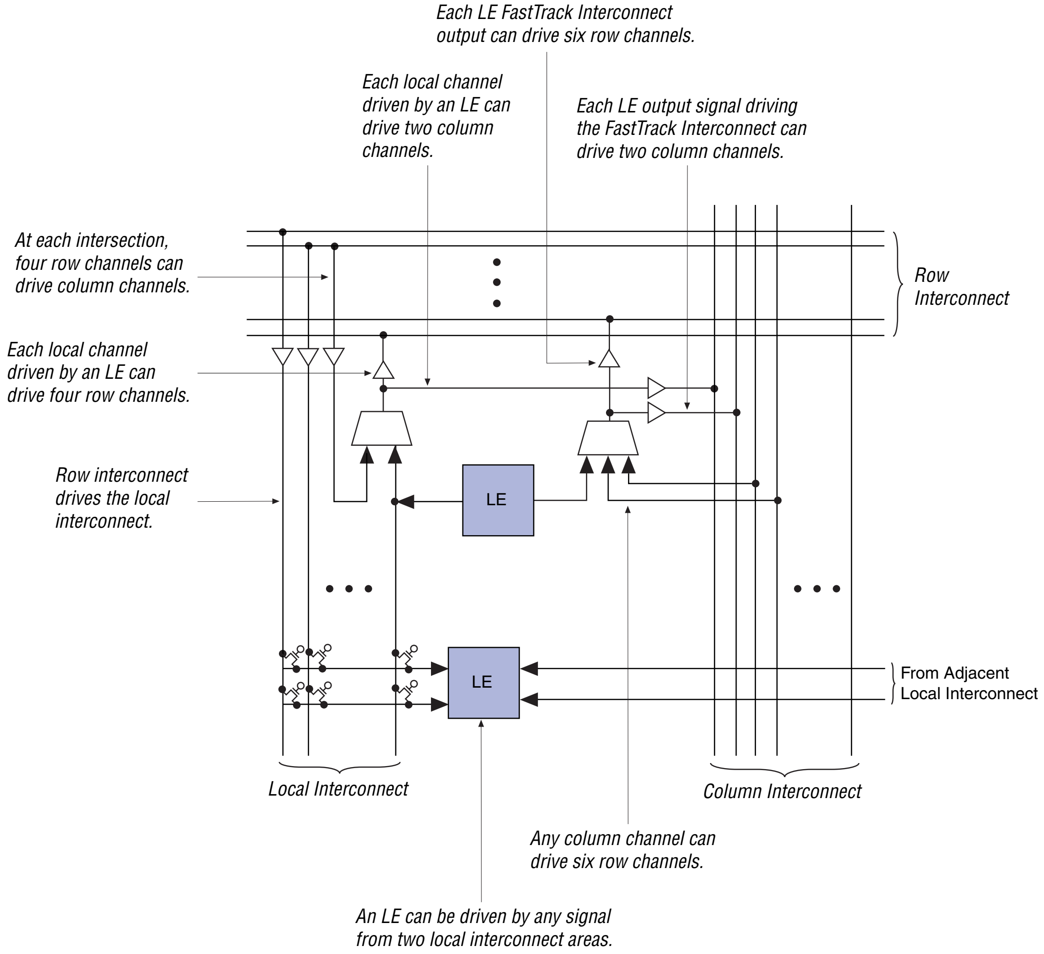
Each column of LABs is served by a dedicated column interconnect. The LEs in an LAB can drive the column interconnect. The LEs in an LAB, a column IOE, or a row interconnect can drive the column interconnect. The column interconnect can then drive another row's interconnect to route the signals to other LABs in the device. A signal from the column interconnect must be routed to the row interconnect before it can enter an LAB.

Each LE has a FastTrack Interconnect output and a local output. The FastTrack interconnect output can drive six row and two column lines directly; the local output drives the local interconnect. Each local interconnect channel driven by an LE can drive four row and two column channels. This feature provides additional flexibility, because each LE can drive any of ten row lines and four column lines.

In addition, LEs can drive global control signals. This feature is useful for distributing internally generated clock, asynchronous clear, and asynchronous preset signals. A pin-driven global signal can also drive data signals, which is useful for high-fan-out data signals.

Each LAB drives two groups of local interconnects, which allows an LE to drive two LABs, or 20 LEs, via the local interconnect. The row-to-local multiplexers are used more efficiently, because the multiplexers can now drive two LABs. Figure 10 shows how an LAB connects to row and column interconnects.

Figure 10. LAB Connections to Row & Column Interconnects



For improved routability, the row interconnect consists of full-length and half-length channels. The full-length channels connect to all LABs in a row; the half-length channels connect to the LABs in half of the row. In addition to providing a predictable, row-wide interconnect, this architecture provides increased routing resources. Two neighboring LABs can be connected using a half-length channel, which saves the other half of the channel for the other half of the row. One-third of the row channels are half-length channels.

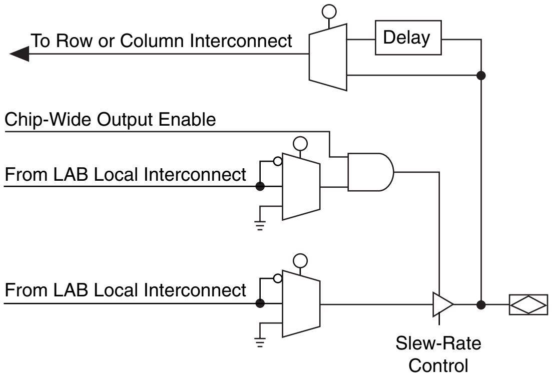
I/O Elements

An IOE contains a bidirectional I/O buffer and a tri-state buffer. IOEs can be used as input, output, or bidirectional pins. An IOE receives its data signals from the adjacent local interconnect, which can be driven by a row or column interconnect (allowing any LE in the device to drive the IOE) or by an adjacent LE (allowing fast clock-to-output delays). A FastFLEX™ I/O pin is a row or column output pin that receives its data signals from the adjacent local interconnect driven by an adjacent LE. The IOE receives its output enable signal through the same path, allowing individual output enables for every pin and permitting emulation of open-drain buffers. The Altera Compiler uses programmable inversion to invert the data or output enable signals automatically where appropriate. Open-drain emulation is provided by driving the data input low and toggling the OE of each IOE. This emulation is possible because there is one OE per pin.

A chip-wide output enable feature allows the designer to disable all pins of the device by asserting one pin (`DEV_OE`). This feature is useful during board debugging or testing.

Figure 12 shows the IOE block diagram.

Figure 12. IOE Block Diagram



Open-drain output pins on 5.0-V or 3.3-V FLEX 6000 devices (with a pull-up resistor to the 5.0-V supply) can drive 5.0-V CMOS input pins that require a V_{IH} of 3.5 V. When the open-drain pin is active, it will drive low. When the pin is inactive, the trace will be pulled up to 5.0 V by the resistor. The open-drain pin will only drive low or tri-state; it will never drive high. The rise time is dependent on the value of the pull-up resistor and load impedance. The I_{OL} current specification should be considered when selecting a pull-up resistor.

Output pins on 5.0-V FLEX 6000 devices with V_{CCIO} = 3.3 V or 5.0 V (with a pull-up resistor to the 5.0-V supply) can also drive 5.0-V CMOS input pins. In this case, the pull-up transistor will turn off when the pin voltage exceeds 3.3 V. Therefore, the pin does not have to be open-drain.

Power Sequencing & Hot-Socketing

Because FLEX 6000 family devices can be used in a mixed-voltage environment, they have been designed specifically to tolerate any possible power-up sequence. The V_{CCIO} and V_{CCINT} power planes can be powered in any order.

Signals can be driven into 3.3-V FLEX 6000 devices before and during power up without damaging the device. Additionally, FLEX 6000 devices do not drive out during power up. Once operating conditions are reached, FLEX 6000 devices operate as specified by the user.

IEEE Std. 1149.1 (JTAG) Boundary-Scan Support

All FLEX 6000 devices provide JTAG BST circuitry that comply with the IEEE Std. 1149.1-1990 specification. Table 8 shows JTAG instructions for FLEX 6000 devices. JTAG BST can be performed before or after configuration, but not during configuration (except when you disable JTAG support in user mode).

1 See *Application Note 39 (IEEE 1149.1 (JTAG) Boundary-Scan Testing in Altera Devices)* for more information on JTAG BST circuitry.

Table 8. FLEX 6000 JTAG Instructions

JTAG Instruction	Description
SAMPLE/PRELOAD	Allows a snapshot of the signals at the device pins to be captured and examined during normal device operation, and permits an initial data pattern to be output at the device pins.
EXTEST	Allows the external circuitry and board-level interconnections to be tested by forcing a test pattern at the output pins and capturing test result at the input pins.
BYPASS	Places the 1-bit bypass register between the `TDI` and `TDO` pins, which allows the BST data to pass synchronously through the selected device to adjacent devices during normal device operation.

The instruction register length for FLEX 6000 devices is three bits. Table 9 shows the boundary-scan register length for FLEX 6000 devices.

Table 9. FLEX 6000 Device Boundary-Scan Register Length

Device	Boundary-Scan Register Length
EPF6010A	522
EPF6016	621
EPF6016A	522
EPF6024A	666

FLEX 6000 devices include a weak pull-up on JTAG pins.

See *Application Note 39 (IEEE 1149.1 (JTAG) Boundary-Scan Testing in Altera Devices)* for more information.

Figure 16 shows the timing requirements for the JTAG signals.

Figure 16. JTAG Waveforms

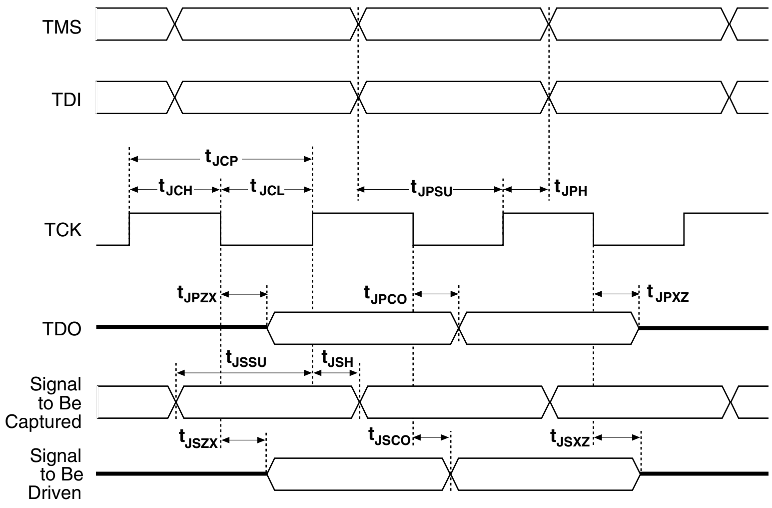


Table 10 shows the JTAG timing parameters and values for FLEX 6000 devices.

Table 10. JTAG Timing Parameters & Values

Symbol	Parameter	Min	Max	Unit
t_{JCP}	`TCK` clock period	100		ns
t_{JCH}	`TCK` clock high time	50		ns
t_{JCL}	`TCK` clock low time	50		ns
t_{JPSU}	JTAG port setup time	20		ns
t_{JPH}	JTAG port hold time	45		ns
t_{JPCO}	JTAG port clock-to-output		25	ns
t_{JPZX}	JTAG port high impedance to valid output		25	ns
t_{JPXZ}	JTAG port valid output to high impedance		25	ns
t_{JSSU}	Capture register setup time	20		ns
t_{JSH}	Capture register hold time	45		ns
t_{JSCO}	Update register clock-to-output		35	ns
t_{JSZX}	Update register high impedance to valid output		35	ns
t_{JSXZ}	Update register valid output to high impedance		35	ns

Generic Testing

Each FLEX 6000 device is functionally tested. Complete testing of each configurable SRAM bit and all logic functionality ensures 100% configuration yield. AC test measurements for FLEX 6000 devices are made under conditions equivalent to those shown in Figure 17. Multiple test patterns can be used to configure devices during all stages of the production flow.

Figure 17. AC Test Conditions

Power supply transients can affect AC measurements. Simultaneous transitions of multiple outputs should be avoided for accurate measurement. Threshold tests must not be performed under AC conditions. Large-amplitude, fast-ground-current transients normally occur as the device outputs discharge the load capacitances. When these transients flow through the parasitic inductance between the device ground pin and the test system ground, significant reductions in observable noise immunity can result. Numbers without parentheses are for 5.0-V devices or outputs. Numbers in parentheses are for 3.3-V devices or outputs. Numbers in brackets are for 2.5-V devices or outputs.

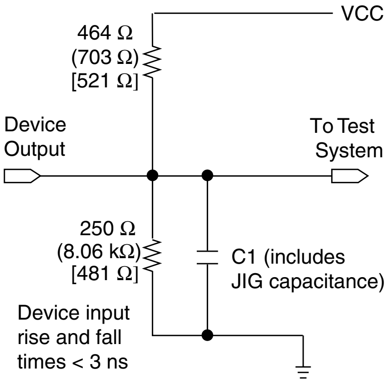


Table 15. FLEX 6000 3.3-V Device Absolute Maximum Ratings *Note (1)*

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply voltage	With respect to ground *(2)*	–0.5	4.6	V
V_I	DC input voltage		–2.0	5.75	V
I_{OUT}	DC output current, per pin		–25	25	mA
T_{STG}	Storage temperature	No bias	–65	150	° C
T_{AMB}	Ambient temperature	Under bias	–65	135	° C
T_J	Junction temperature	PQFP, PLCC, and BGA packages		135	° C

Table 16. FLEX 6000 3.3-V Device Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CCINT}	Supply voltage for internal logic and input buffers	*(3)*, *(4)*	3.00 (3.00)	3.60 (3.60)	V
V_{CCIO}	Supply voltage for output buffers, 3.3-V operation	*(3)*, *(4)*	3.00 (3.00)	3.60 (3.60)	V
	Supply voltage for output buffers, 2.5-V operation	*(3)*, *(4)*	2.30 (2.30)	2.70 (2.70)	V
V_I	Input voltage		–0.5	5.75	V
V_O	Output voltage		0	V_{CCIO}	V
T_J	Operating temperature	For commercial use	0	85	° C
		For industrial use	–40	100	° C
t_R	Input rise time			40	ns
t_F	Input fall time			40	ns

Timing Model

The continuous, high-performance FastTrack Interconnect routing resources ensure predictable performance and accurate simulation and timing analysis. This predictable performance contrasts with that of FPGAs, which use a segmented connection scheme and therefore have unpredictable performance.

Device performance can be estimated by following the signal path from a source, through the interconnect, to the destination. For example, the registered performance between two LEs on the same row can be calculated by adding the following parameters:

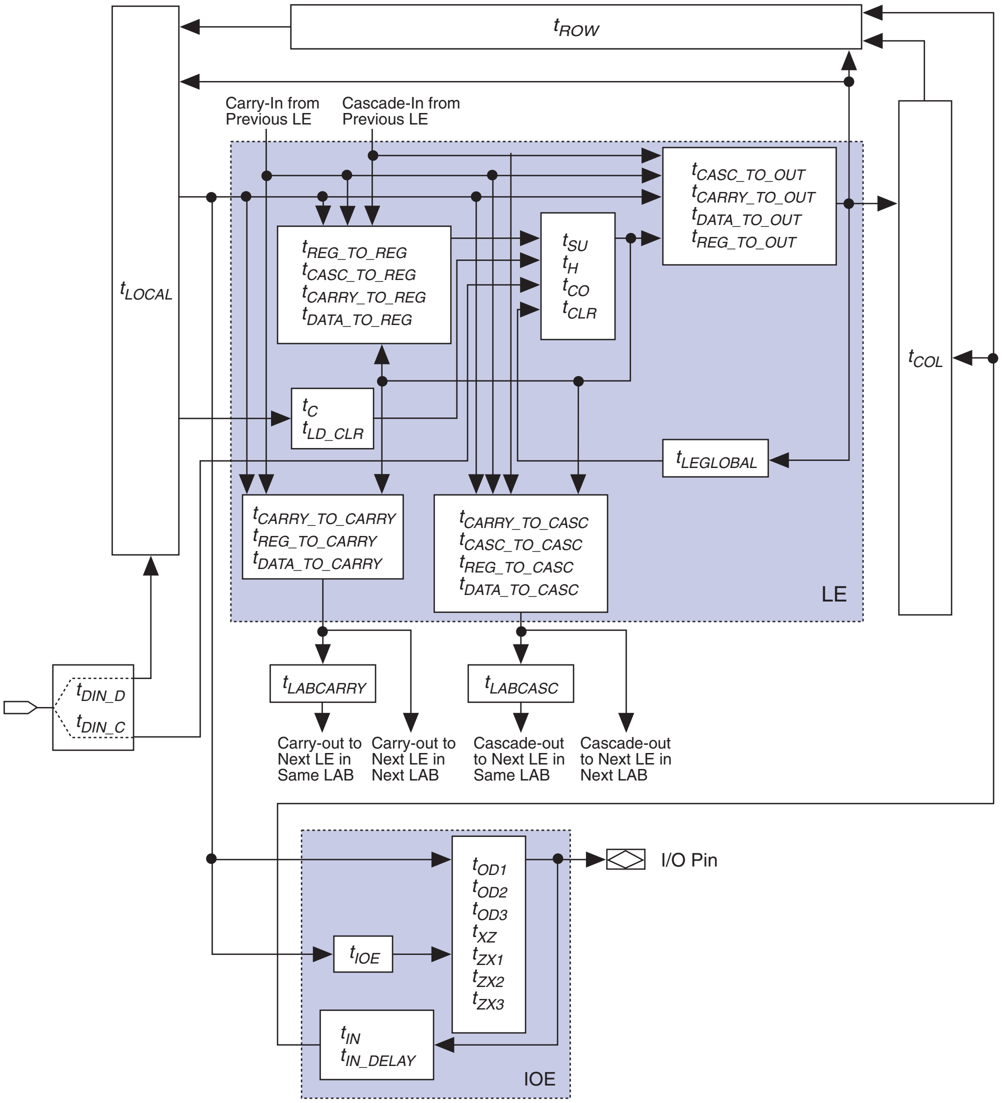
- LE register clock-to-output delay ($t_{CO} + t_{REG\_TO\_OUT}$)
- Routing delay ($t_{ROW} + t_{LOCAL}$)
- LE LUT delay ($t_{DATA\_TO\_REG}$)
- LE register setup time (t_{SU})

The routing delay depends on the placement of the source and destination LEs. A more complex registered path may involve multiple combinatorial LEs between the source and destination LEs.

Timing simulation and delay prediction are available with the Simulator and Timing Analyzer, or with industry-standard EDA tools. The Simulator offers both pre-synthesis functional simulation to evaluate logic design accuracy and post-synthesis timing simulation with 0.1-ns resolution. The Timing Analyzer provides point-to-point timing delay information, setup and hold time analysis, and device-wide performance analysis.

Figure 19 shows the overall timing model, which maps the possible routing paths to and from the various elements of the FLEX 6000 device.

Figure 19. FLEX 6000 Timing Model



Tables 19 through 21 describe the FLEX 6000 internal timing microparameters, which are expressed as worst-case values. Using hand calculations, these parameters can be used to estimate design performance. However, before committing designs to silicon, actual worst-case performance should be modeled using timing simulation and timing analysis. Tables 22 and 23 describe FLEX 6000 external timing parameters.

Table 19. LE Timing Microparameters *Note (1)*

Symbol	Parameter	Conditions
$t_{REG\_TO\_REG}$	LUT delay for LE register feedback in carry chain	
$t_{CASC\_TO\_REG}$	Cascade-in to register delay	
$t_{CARRY\_TO\_REG}$	Carry-in to register delay	
$t_{DATA\_TO\_REG}$	LE input to register delay	
$t_{CASC\_TO\_OUT}$	Cascade-in to LE output delay	
$t_{CARRY\_TO\_OUT}$	Carry-in to LE output delay	
$t_{DATA\_TO\_OUT}$	LE input to LE output delay	
$t_{REG\_TO\_OUT}$	Register output to LE output delay	
t_{SU}	LE register setup time before clock; LE register recovery time after asynchronous clear	
t_{H}	LE register hold time after clock	
t_{CO}	LE register clock-to-output delay	
t_{CLR}	LE register clear delay	
t_{C}	LE register control signal delay	
t_{LD_CLR}	Synchronous load or clear delay in counter mode	
$t_{CARRY\_TO\_CARRY}$	Carry-in to carry-out delay	
$t_{REG\_TO\_CARRY}$	Register output to carry-out delay	
$t_{DATA\_TO\_CARRY}$	LE input to carry-out delay	
$t_{CARRY\_TO\_CASC}$	Carry-in to cascade-out delay	
$t_{CASC\_TO\_CASC}$	Cascade-in to cascade-out delay	
$t_{REG\_TO\_CASC}$	Register-out to cascade-out delay	
$t_{DATA\_TO\_CASC}$	LE input to cascade-out delay	
t_{CH}	LE register clock high time	
t_{CL}	LE register clock low time	

Table 20. IOE Timing Microparameters *Note (1)*

Symbol	Parameter	Conditions
t_{OD1}	Output buffer and pad delay, slow slew rate = off, V_{CCIO} = V_{CCINT}	C1 = 35 pF *(2)*
t_{OD2}	Output buffer and pad delay, slow slew rate = off, V_{CCIO} = low voltage	C1 = 35 pF *(3)*
t_{OD3}	Output buffer and pad delay, slow slew rate = on	C1 = 35 pF *(4)*
t_{XZ}	Output buffer disable delay	C1 = 5 pF
t_{ZX1}	Output buffer enable delay, slow slew rate = off, V_{CCIO} = V_{CCINT}	C1 = 35 pF *(2)*
t_{ZX2}	Output buffer enable delay, slow slew rate = off, V_{CCIO} = low voltage	C1 = 35 pF *(3)*
t_{ZX3}	IOE output buffer enable delay, slow slew rate = on	C1 = 35 pF *(4)*
t_{IOE}	Output enable control delay	
t_{IN}	Input pad and buffer to FastTrack Interconnect delay	
t_{IN_DELAY}	Input pad and buffer to FastTrack Interconnect delay with additional delay turned on	

Table 21. Interconnect Timing Microparameters *Note (1)*

Symbol	Parameter	Conditions
t_{LOCAL}	LAB local interconnect delay	
t_{ROW}	Row interconnect routing delay	*(5)*
t_{COL}	Column interconnect routing delay	*(5)*
t_{DIN_D}	Dedicated input to LE data delay	*(5)*
t_{DIN_C}	Dedicated input to LE control delay	
$t_{LEGLOBAL}$	LE output to LE control via internally-generated global signal delay	*(5)*
$t_{LABCARRY}$	Routing delay for the carry-out of an LE driving the carry-in signal of a different LE in a different LAB	
$t_{LABCASC}$	Routing delay for the cascade-out signal of an LE driving the cascade-in signal of a different LE in a different LAB	

Table 22. External Reference Timing Parameters

Symbol	Parameter	Conditions
t_1	Register-to-register test pattern	*(6)*
t_{DRR}	Register-to-register delay via 4 LEs, 3 row interconnects, and 4 local interconnects	*(7)*

Table 30. IOE Timing Microparameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
t_{OD3}		4.7		5.2	ns
t_{XZ}		2.3		2.8	ns
t_{ZX1}		2.3		2.8	ns
t_{ZX2}		4.6		5.1	ns
t_{ZX3}		4.7		5.2	ns
t_{IOE}		0.5		0.6	ns
t_{IN}		3.3		4.0	ns
t_{IN_DELAY}		4.6		5.6	ns

Table 31. Interconnect Timing Microparameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
t_{LOCAL}		0.8		1.0	ns
t_{ROW}		2.9		3.3	ns
t_{COL}		2.3		2.5	ns
t_{DIN_D}		4.9		6.0	ns
t_{DIN_C}		4.8		6.0	ns
$t_{LEGLOBAL}$		3.1		3.9	ns
$t_{LABCARRY}$		0.4		0.5	ns
$t_{LABCASC}$		0.8		1.0	ns

Table 32. External Reference Timing Parameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
$\mathbf{t_1}$		53.0		65.0	ns
$\mathbf{t_{DRR}}$		16.0		20.0	ns

Table 33. External Timing Parameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
t_{INSU}	3.2		4.1		ns
t_{INH}	0.0		0.0		ns
t_{OUTCO}	2.0	7.9	2.0	9.9	ns

Tables 34 through 38 show the timing information for EPF6024A devices.

Table 34. LE Timing Microparameters for EPF6024A Devices

Parameter	Speed Grade						Unit
	-1		-2		-3		
	Min	Max	Min	Max	Min	Max	
$t_{REG\_TO\_REG}$		1.2		1.3		1.6	ns
$t_{CASC\_TO\_REG}$		0.7		0.8		1.0	ns
$t_{CARRY\_TO\_REG}$		1.6		1.8		2.2	ns
$t_{DATA\_TO\_REG}$		1.3		1.4		1.7	ns
$t_{CASC\_TO\_OUT}$		1.2		1.3		1.6	ns
$t_{CARRY\_TO\_OUT}$		2.0		2.2		2.6	ns
$t_{DATA\_TO\_OUT}$		1.8		2.1		2.6	ns
$t_{REG\_TO\_OUT}$		0.3		0.3		0.4	ns
t_{SU}	0.9		1.0		1.2		ns
t_{H}	1.3		1.4		1.7		ns
t_{CO}		0.2		0.3		0.3	ns
t_{CLR}		0.3		0.3		0.4	ns
t_{C}		1.9		2.1		2.5	ns
t_{LD_CLR}		1.9		2.1		2.5	ns
$t_{CARRY\_TO\_CARRY}$		0.2		0.2		0.3	ns
$t_{REG\_TO\_CARRY}$		1.4		1.6		1.9	ns
$t_{DATA\_TO\_CARRY}$		1.3		1.4		1.7	ns
$t_{CARRY\_TO\_CASC}$		1.1		1.2		1.4	ns
$t_{CASC\_TO\_CASC}$		0.7		0.8		1.0	ns
$t_{REG\_TO\_CASC}$		1.4		1.6		1.9	ns
$t_{DATA\_TO\_CASC}$		1.0		1.1		1.3	ns
t_{CH}	2.5		3.0		3.5		ns
t_{CL}	2.5		3.0		3.5		ns

Table 38. External Timing Parameters for EPF6024A Devices

Parameter	Speed Grade						Unit
	-1		-2		-3		
	Min	Max	Min	Max	Min	Max	
t_{INSU}	2.0 (1)		2.2 (1)		2.6 (1)		ns
t_{INH}	0.2 (2)		0.2 (2)		0.3 (2)		ns
t_{OUTCO}	2.0	7.4	2.0	8.2	2.0	9.9	ns

Notes:

(1) Setup times are longer when the *Increase Input Delay* option is turned on. The setup time values are shown with the *Increase Input Delay* option turned off.

(2) Hold time is zero when the *Increase Input Delay* option is turned on.

Power Consumption

The supply power (P) for FLEX 6000 devices can be calculated with the following equations:

$$P = P_{INT} + P_{IO}$$
$$P = (I_{CCSTANDBY} + I_{CCACTIVE}) \times V_{CC} + P_{IO}$$

Typical $I_{CCSTANDBY}$ values are shown as I_{CC0} in the "FLEX 6000 Device DC Operating Conditions" table on pages 31 and 33 of this data sheet. The $I_{CCACTIVE}$ value depends on the switching frequency and the application logic. This value is based on the amount of current that each LE typically consumes. The P_{IO} value, which depends on the device output load characteristics and switching frequency, can be calculated using the guidelines given in *Application Note 74 (Evaluating Power for Altera Devices)*.

The $I_{CCACTIVE}$ value can be calculated with the following equation:

$$I_{CCACTIVE} = K \times \mathbf{f_{MAX}} \times N \times \mathbf{tog_{LC}} \times \frac{\mu A}{MHz \times LE}$$

Where:

$\mathbf{f_{MAX}}$ = Maximum operating frequency in MHz
N = Total number of LEs used in a FLEX 6000 device
$\mathbf{tog_{LC}}$ = Average percentage of LEs toggling at each clock (typically 12.5%)
K = Constant, shown in Table 39

Table 39. K Constant Values

Device	K Value
EPF6010A	14
EPF6016	88
EPF6016A	14
EPF6024A	14

Device Pin-Outs

See the Altera web site (**http://www.altera.com**) or the *Altera Digital Library* for pin-out information.